NSN 5962-01-324-2478

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Body Length:
Between 1.435 inches and 1.485 inches
Body Width:
Between 0.515 inches and 0.600 inches
Body Height:
Between 0.140 inches and 0.185 inches
Operating Tempurature Range:
-55.0/+125.0 degrees celsius
Storage Tempurature Range:
-65.0/+150.0 degrees celsius
End Application:
Mu-935/wlq-4
Features Provided:
Hermetically sealed and burn in and programmable and ultraviolet erasable and w/enable
Inclosure Material:
Ceramic
Inclosure Configuration:
Dual-in-line Dual-in-line
Output Logic Form:
N-type metal oxide-semiconductor logic
Input Circuit Pattern:
17 input
Terminal Surface Treatment:
Solder
Voltage Rating And Type Per Characteristic:
6.5 volts power source
Time Rating Per Chacteristic:
200.00 nanoseconds propagation delay time, low to high level output and 200.00 nanoseconds propagation delay time, high to low level
output
Memory Device Type:
Rom
Memory Capacity:
Unknown
Test Data Document:
96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).
Terminal Type And Quantity:
28 printed circuit
Shelf Life:
N/a
Unit Of Measure:

Yes - demil/mli

Demilitarization:

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